



Product Brief

OptiMOS™ 5 40 V in S3O8 Package

Infineon's Latest Generation of Automotive Power MOSFETs

High Power MOSFETs in S308 (PG-TSDSON-8)

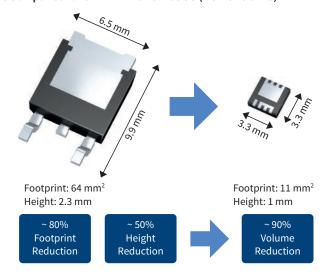
Infineon's new OptiMOSTM 5 40 V product family in S308 package combines leading power MOSFET technology with 3.3 x 3.3 mm leadless power package for very compact & robust automotive system solutions.

OptiMOSTM 5 40 V S308 products are based on Infineon's latest silicon automotive PowerMOS technology, optimized to meet and exceed the energy efficiency and power density requirements of automotive BLDC and H-bridge applications. In combination with Infineon's robust S308 leadless package technology, it enables very small and efficient systems designs with minimal $R_{DS(on)}$ down to 2.8 m Ω .

Applications

Brushless DC & Brushed DC drives in body, powertrain and safety applications.

Footprint Comparison: 40 A DPAK vs 40 A S308 (PG-TSDSON-8)



Key Features

- $R_{DS(on)}$: 2.8–8.4 m Ω
- S308 Pack: 3.3 x 3.3 mm (PG-TSDSON-8)
- Q_G: max. 40 nC
- Optimized: FOM, C_{iss}, C_{oss}

Technical Key Benefits

- Up to 250 W BLDC drives
- Small package footprint
- Low gate charge @ 2.8 Ω
- Soft switching behavior
- High thermal robustness

Customer Benefits

- High power density
- Compact system design
- Reduced driver costs
- Low EMI on system level
- High system reliability

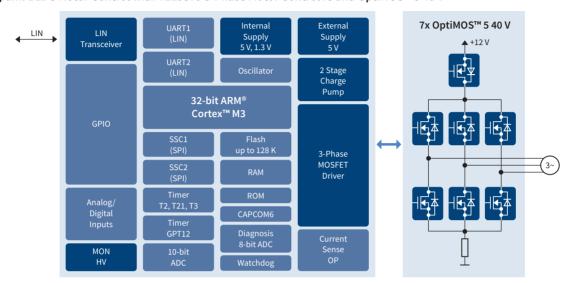




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Block Diagram: BLDC Motor Control with TLE9879 3-Phase Motor Control IC and OptiMOS™ 5 40 V



System Design

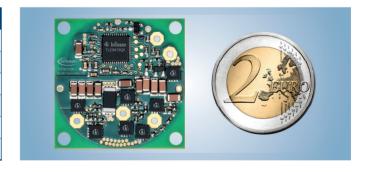
- OptiMOS[™] 5 40 V S308 Automotive Power MOSFETs
- 3rd Generation Infineon Embedded Power IC TLE9879
 3-Phase Motor Control IC
- Sensor-less field oriented control
- Single shunt measurement method

System Performance

- PCB space savings thanks to exceptional small footprints:
 - MOSFETs in S308 (3.3x3.3mm)
 - Infineon Embedded Power, System-on-Chip-Solution in VQFN package (7x7mm)
- Motor system power up to ~ 250 W

Product Summary

Туре	Description	Ordering Code
IPZ40N04S5L-2R8	40 V; 2.8 mΩ logic level	SP001152004
IPZ40N04S5-3R1	40 V; 3.1 mΩ normal level 40 V	SP001152006
IPZ40N04S5L-4R8	40 V; 4.8 mΩ logic level	SP001154302
IPZ40N04S5-5R4	40 V; 5.4 mΩ normal level	SP001153440
IPZ40N04S5L-7R4	40 V; 7.4 mΩ logic level	SP001153436
IPZ40N04S5-8R4	40 V; 8.4 mΩ normal level	SP001153438



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